











	<b>ZXMN6A08GTA</b>	
	<b>Hersteller-Teilenummer:</b>	ZXMN6A08GTA
	<b>Hersteller / Marke:</b>	Diodes Incorporated
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 60V 3.8A SOT223
	<b>Datenblätter:</b>	 <a href="#">ZXMN6A08GTA.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 262911 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	ZXMN6A08GTA
Hersteller	Diodes Incorporated
Beschreibung	MOSFET N-CH 60V 3.8A SOT223
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	262911 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-261-4, TO-261AA
Supplier Device-Gehäuse	SOT-223
Verlustleistung (max)	2W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.8A (Ta)
Rds On (Max) @ Id, Vgs	80 mOhm @ 4.8A, 10V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5.8nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	459pF @ 40V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































ZXMN6A08GTA ist neu im Original, Suche ZXMN6A08GTA Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ZXMN6A08GTA Diodes Incorporated mit Garantie und Vertrauen. Anfrage ZXMN6A08GTA: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>ZXMN6A08E6TC</b> Diodes Incorporated MOSFET N-CH 60V 2.8A SOT23-6</p>	 <p><b>ZXMN6A08K</b> DIODES ZXMN6A08K DIODES</p>	 <p><b>ZXMN6A08GQTA</b> Diodes Incorporated MOSFET N-CH 60VSOT223</p>	 <p><b>ZXMN6A08GTC</b> Z Z SOT223-3</p>
 <p><b>ZXMN6A09DN8</b> Diodes ZXMN6A09DN8 Diodes</p>	 <p><b>ZXMN6A08GQ</b> DIODES ZXMN6A08GQ DIODES</p>	 <p><b>ZXMN6A08KTC</b> Diodes Incorporated MOSFET N-CH 60V 5.36A DPAK</p>	 <p><b>ZXMN6A08G</b> DIODES ZXMN6A08G DIODES</p>

### heiße Teile

Mehr

 ZXMN3F31DN8TC	 ZXMN3G32DN8	 ZXMN3G32DN8TA	 ZXMN3G32DN8TC	 ZXMN4A06G
 ZXMN4A06GQ	 ZXMN4A06GQTA	 ZXMN4A06GTA	 ZXMN4A06GTC	 ZXMN4A06K
 ZXMN4A06KTC	 ZXMN4A16GTA	 ZXMN61N02FTA	 ZXMN62N02E6TA	 ZXMN62N03E6TA
 ZXMN62P02E6TA	 ZXMN62P03E6TA	 ZXMN6A07F-7-88	 ZXMN6A07FTA	 ZXMN6A07FTC
 ZXMN6A07ZTA	 ZXMN6A08E6QTA	 ZXMN6A08E6TA	 ZXMN6A08G	 ZXMN6A08GQ
 ZXMN6A08K	 ZXMN6A08KTC	 ZXMN6A09DN8	 ZXMN6A09DN8TA	 ZXMN6A09DN8TC
 ZXMN6A09G	 ZXMN6A09GTA	 ZXMN6A09GTC	 ZXMN6A09K	 ZXMN6A09KTC
 ZXMN6A11D	 ZXMN6A11DN8	 ZXMN6A11DN8TA	 ZXMN6A11G	 ZXMN6A11GTA
 ZXMN6A11ZTA	 ZXMN6A25DN8	 ZXMN6A25DN8TA	 ZXMN6A25DN8TC	 ZXMN6A25G
 ZXMN6A25GTA	 ZXMN6A25K	 ZXMN6A25KTC	 ZXMN6A25N8	 ZXMN6A25N8TA

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited